### SN74LVC16544 16-BIT REGISTERED TRANSCEIVER WITH 3-STATE OUTPUTS

DGG OR DL PACKAGE

(TOP VIEW)

SCAS351 - MARCH 1994

### Member of the Texas Instruments Widebus™ Family

- EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process
- Typical V<sub>OLP</sub> (Output Ground Bounce)
  < 0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)
  2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Bus-Hold On Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages

### description

This 16-bit registered transceiver is designed for low-voltage (3.3 V)  $V_{CC}$  operation.

The SN74LVC16544 can be used as two 8-bit transceivers or one 16-bit transceiver. Separate latch-enable (LEAB or LEBA) and output-enable (OEAB or OEBA) inputs are provided for each register to permit independent control in either direction of data flow.

The A-to-B enable (CEAB) input must be low in order to enter data from A or to output data from B. If CEAB is low and LEAB is low, the A-to-B latches are transparent; a subsequent low-to-high transition of LEAB puts the A latches in the storage mode. With CEAB and OEAB both low, the 3-state

56 10EBA 10EAB 1LEAB 55 1 1 LEBA 2 1CEAB 54 1CEBA 3 **GND** 4 53 GND 1A1 5 52 1 1B1 51 1B2 1A2 [ 6 V<sub>CC</sub> L 7 50 V<sub>CC</sub> 1A3 📙 8 49 🛮 1B3 1A4 Π 9 48**∏** 1B4 47 1B5 1A5 10 GND [ 46Π GND 11 1A6 Π 45 ¶ 1B6 12 44 1 1B7 1A7 13 1A8 🛮 43 1B8 14 2A1 Π 15 42**∏** 2B1 2A2 41 **□** 2B2 16 2A3 40**∏** 2B3 17 GND [] 39 **∏** GND 18 2A4 38**∏** 2B4 19 2A5 🛮 37**∏** 2B5 20 2A6 🛮 36**∏** 2B6 21  $V_{CC}$ 22 35 V<sub>CC</sub> 2A7 🛮 23 34**∏** 2B7 2A8 Π 24 33**∏** 2B8 GND [ 25 32 **∏** GND 2CEAB 31 7 2CEBA 26 2LEAB 27 30 **□** 2LEBA 2OEBA 20EAB 28 29∏

B outputs are active and reflect the data present at the output of the A latches. Data flow from B to A is similar but requires using the  $\overline{\text{CEBA}}$ ,  $\overline{\text{LEBA}}$ , and  $\overline{\text{OEBA}}$  inputs.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74LVC16544 is characterized for operation from -40°C to 85°C.

# FUNCTION TABLE† (each 8-bit section)

| INPUTS |      |      | OUTPUT |                  |
|--------|------|------|--------|------------------|
| CEAB   | LEAB | OEAB | Α      | В                |
| Н      | Х    | Х    | Χ      | Z                |
| L      | Χ    | Н    | Χ      | Z                |
| L      | Н    | L    | Χ      | в <sub>0</sub> ‡ |
| L      | L    | L    | L      | Н                |
| L      | L    | L    | Н      | L                |

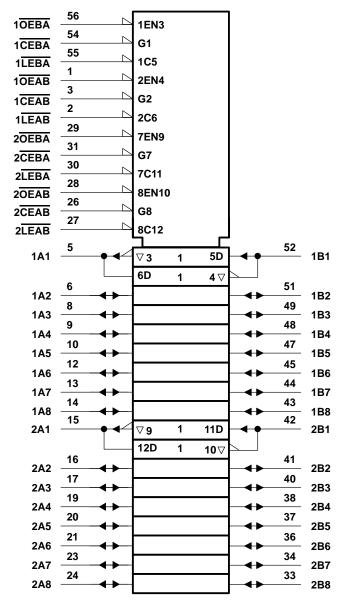
<sup>†</sup> A-to-B data flow is shown; B-to-A flow control is the same except that it uses CEBA, LEBA, and OEBA.

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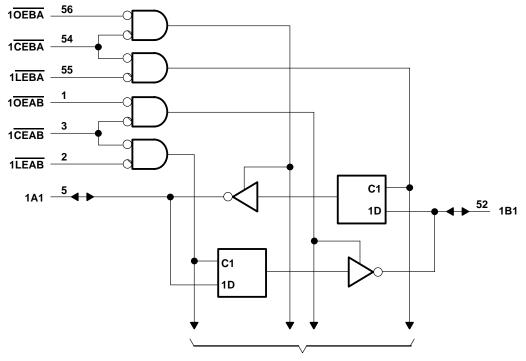
<sup>&</sup>lt;sup>‡</sup> Output level before the indicated steady-state input conditions were established.

### logic symbol†

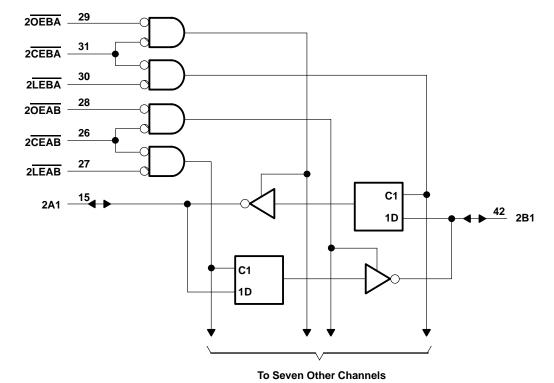


<sup>&</sup>lt;sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## logic diagram (positive logic)



To Seven Other Channels





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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

| Supply voltage range, V <sub>CC</sub>   | 0.5 V to 4.6 V                             |
|---|--|
| Input voltage range, V <sub>I</sub> (except I/O ports) (see Note 1)                             | 0.5 V to 4.6 V                             |
| Input voltage range, V <sub>I</sub> (I/O ports) (see Notes 1 and 2)                             | $\dots$ -0.5 V to V <sub>CC</sub> + 0.5 V  |
| Output voltage range, V <sub>O</sub> (see Notes 1 and 2)  | $-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$ |
| Input clamp current, $I_{IK}$ ( $V_I < 0$ )   | –50 mA                                     |
| Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> ) | ±50 mA                                     |
| Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$                                    | ±50 mA                                     |
| Continuous current through V <sub>CC</sub> or GND   | ±100 mA                                    |
| Maximum power dissipation at $T_A = 55^{\circ}$ C (in still air): DGG package                   | 1 W  |
| DL package  | 1.4 W                                      |
| Storage temperature range   | −65°C to 150°C                             |

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### recommended operating conditions (see Note 3)

|                |                                    |  | MIN | MAX | UNIT |  |
|----------------|------------------------------------|--|-----|-----|------|--|
| VCC            | Supply voltage                     |  |     | 3.6 | V    |  |
| $V_{IH}$       | High-level input voltage           | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | 2   |     | V    |  |
| $\vee_{IL}$    | Low-level input voltage            | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ |     | 0.8 | V    |  |
| ٧ <sub>I</sub> | Input voltage                      |  | 0   | VCC | V    |  |
| ٧o             | Output voltage                     |  | 0   | VCC | V    |  |
| ЮН             | High-level output current          | $V_{CC} = 2.7 \text{ V}$                   |     | -12 | 2 mA |  |
|                |                                    | V <sub>CC</sub> = 3 V                      |     | -24 | IIIA |  |
| loL            | Low-level output current           | $V_{CC} = 2.7 \text{ V}$                   |     |     | mA   |  |
|                | Low-level output current           | V <sub>CC</sub> = 3 V                      |     | 24  |      |  |
| Δt/Δν          | Input transition rise or fall rate |  | 0   | 10  | ns/V |  |
| T <sub>A</sub> | Operating free-air temperature     |  | -40 | 85  | °C   |  |

NOTE 3: Unused or floating control pins must be held high or low.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

<sup>2.</sup> This value is limited to 4.6 V maximum.

# PRODUCT PREVIEW

### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PA              | RAMETER                  | TEST CONDITIONS   | v <sub>cc</sub> † | MIN                | MAX  | UNIT          |  |
|-----------------|--------------------------|---|-------------------|--------------------|------|---------------|--|
| VOH             |                          | $I_{OH} = -100 \mu\text{A}$   | MIN to MAX        | V <sub>CC</sub> -0 | .2   |               |  |
|                 |                          | I <sub>OH</sub> = -12 mA  | 2.7 V             | 2.2                |      | V             |  |
|                 |                          | IOH = - 12 IIIA   | 3 V               | 2.4                |      |               |  |
|                 |                          | $I_{OH} = -24 \text{ mA}$   | 3 V               | 2                  |      |               |  |
|                 | I <sub>OL</sub> = 100 μA |   | MIN to MAX        |                    | 0.2  |               |  |
| V <sub>OL</sub> |                          | I <sub>OL</sub> = 12 mA   | 2.7 V             |                    | 0.4  | 0.4 V<br>0.55 |  |
|                 |                          | I <sub>OL</sub> = 24 mA   | 3 V               |                    | 0.55 |               |  |
| IĮ              | Control inputs           | V <sub>I</sub> = V <sub>CC</sub> or GND   | 3.6 V             |                    | ±5   | μΑ            |  |
|                 | A or D norto             | V <sub>I</sub> = 0.8 V  | 3 V               | 75                 |      | μΑ            |  |
| l(hold)         | A or B ports             | V <sub>I</sub> = 2 V  | 3 V               | -75                |      |               |  |
| loz‡            |                          | $V_O = V_{CC}$ or GND   | 3.6 V             |                    | ±10  | μΑ            |  |
| Icc             |                          | $V_I = V_{CC}$ or GND, $I_O = 0$  | 3.6 V             |                    | 40   | μΑ            |  |
| ΔICC            |                          | $V_{CC}$ = 3 V to 3.6 V, One input at $V_{CC}$ – 0.6 V, Other inputs at $V_{CC}$ or GND |                   |                    | 500  | μА            |  |
| Ci              | Control inputs           | $V_I = V_{CC}$ or GND   | 3.3 V             |                    |      | pF            |  |
| C <sub>io</sub> | A or B ports             | $V_O = V_{CC}$ or GND   | 3.3 V             |                    |      | pF            |  |

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate values under recommended operating conditions.

 $<sup>\</sup>mbox{\ensuremath{\mbox{\ensuremath}\ensuremath}\ensuremath}}}}}}}}}}}}} \end{tabular between the input leakage current.}}}}} for the input leakage current in the constraint of the constraint of the constraint of the constraint}}}}}}} \end{tabular between the constraint of the constraint}}}}}}}} \end{tabular between the constraint of the constraint$ 

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